

60 V, 6.2 A NPN low VCEsat transistor

16 January 2025

Product data sheet

1. General description

NPN low V_{CEsat} transistor in a medium power and flat lead SOT89 (SC-62) Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS4041PX

2. Features and benefits

- Very low collector-emitter saturation voltage V_{CEsat}
- High collector current capability ${\rm I}_{\rm C}$ and ${\rm I}_{\rm CM}$
- High collector current gain (h_{FE}) at high ${\rm I}_{\rm C}$
- High energy efficiency due to less heat generation
- AEC-Q101 qualified

3. Applications

- Loadswitch
 - Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	60	V
I _C	collector current			-	-	6.2	A
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	15	A
R _{CEsat}	collector-emitter saturation resistance	I_C = 4 A; I_B = 400 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	18	35	mΩ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		С
2	С	collector		
3	В	base	3 2 1 SOT89	B



6. Ordering information

Table 3. Ordering information					
Type number Package					
	Name	Description	Version		
PBSS4041NX	SOT89	plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	<u>SOT89</u>		

7. Marking

Table 4. Marking codes				
Type number	Marking code[1]			
PBSS4041NX	%6F			

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	60	V
V _{CEO}	collector-emitter voltage	open base		-	60	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
I _C	collector current			-	6.2	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	15	А
I _B	base current			-	1	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	600	mW
			[2]	-	1.5	W
			[3]	-	1.45	W
			[4]	-	2.45	W
			[5]	-	2.5	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.

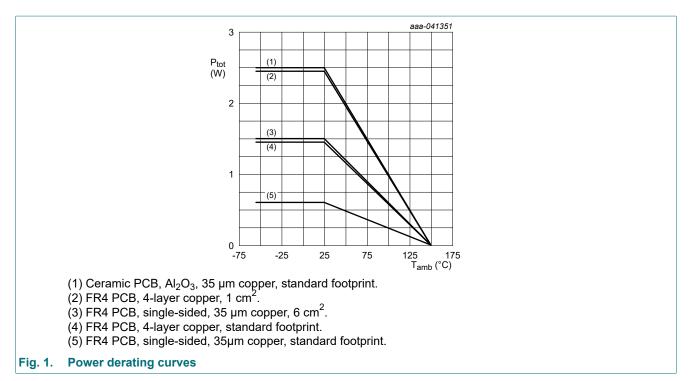
[2] Device mounted on an FR4 PCB, single-sided, $35 \ \mu m$ copper, tin-plated, mounting pad for collector 6 cm².

[3] Device mounted on an FR4 PCB, 4-layer, tin-plated and standard footprint.

[4] Device mounted on an FR4 PCB, 4-layer, tin-plated, mounting pad for collector 1 cm².

[5] Device mounted on a ceramic PCB, Al₂O₃, single-sided, 35 µm copper, tin-plated and standard footprint.

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient	thermal resistance from	in free air	[1]	-	-	208	K/W
	-	[2]	-	-	83	K/W	
			[3]	-	-	86	K/W
			[4]	-	-	51	K/W
	[E	[5]	-	-	50	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	20	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated, mounting pad for collector 6 cm².

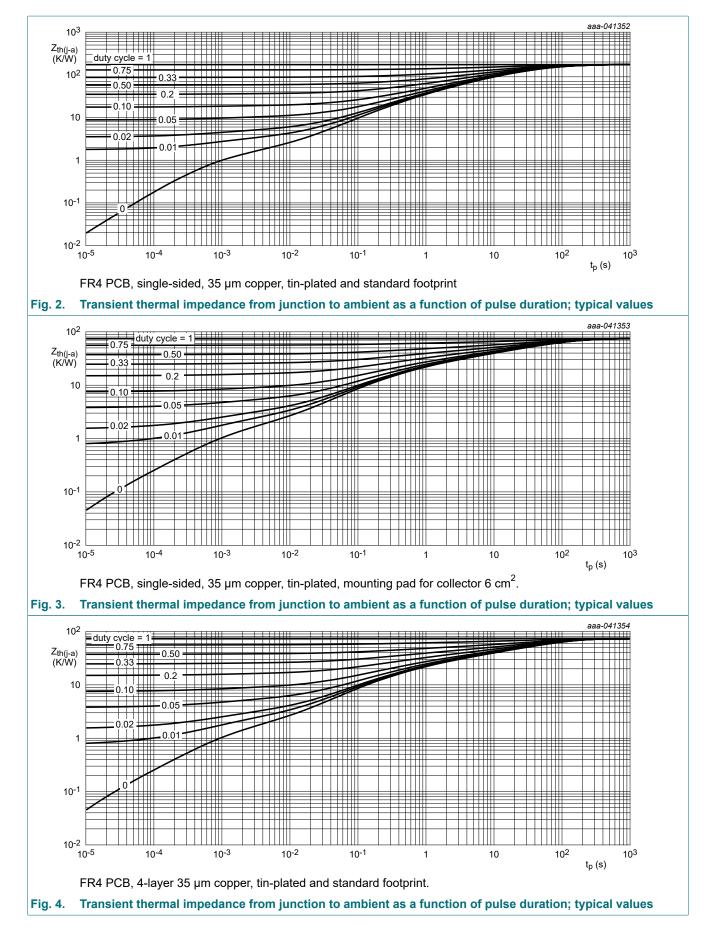
[3] Device mounted on an FR4 PCB, 4-layer, tin-plated and standard footprint.

[4] Device mounted on an FR4 PCB, 4-layer, tin-plated, mounting pad for collector 1 cm²

[5] Device mounted on a ceramic PCB, Al₂O₃, single-sided, 35 µm copper, tin-plated and standard footprint.



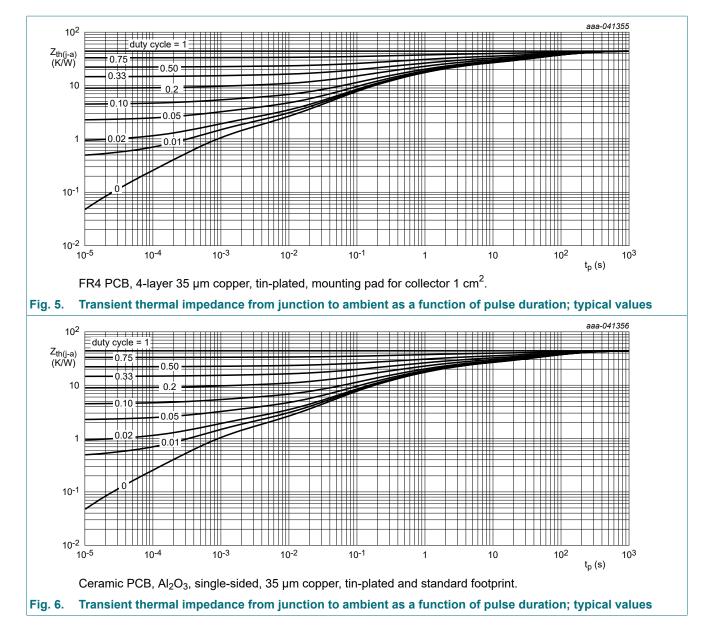
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PBSS4041NX



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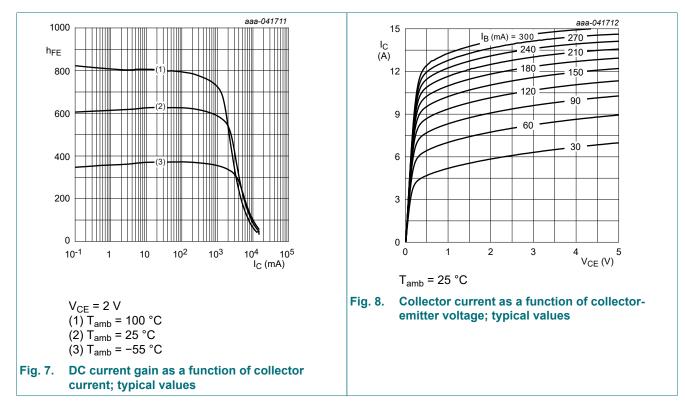
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I_{C} = 100 µA; I_{E} = 0 A; T_{amb} = 25 °C	60	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 10 mA; I _B = 0 A; T _{amb} = 25 °C	60	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	$I_E = 100 \ \mu\text{A}; I_C = 0 \ \text{A}; T_{amb} = 25 \ ^\circ\text{C}$	5	-	-	V
I _{CBO}	collector-base cut-off	$V_{CB} = 60 \text{ V}; \text{ I}_{\text{E}} = 0 \text{ A}; \text{ T}_{\text{amb}} = 25 ^{\circ}\text{C}$	-	-	100	nA
	current	V _{CB} = 60 V; I _E = 0 A; T _j = 150 °C	-	-	50	μA
CES	collector-emitter cut-off current	V_{CE} = 48 V; V_{BE} = 0 V; T_{amb} = 25 °C	-	-	100	nA
ЕВО	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 2 V; I _C = 0.5 A; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	300	525	-	
		V_{CE} = 2 V; I _C = 1 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	300	510	-	
		$ \begin{array}{l} V_{CE} \texttt{= 2 V; } I_{C} \texttt{= 2 A; pulsed; } t_{p} \texttt{\leq 300 } \mu \texttt{s}; \\ \delta \texttt{\leq } 0.02; \; T_{amb} \texttt{= 25 °C} \end{array} $	250	470	-	
		V_{CE} = 2 V; I _C = 4 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	150	280	-	
	V_{CE} = 2 V; I _C = 6 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	75	170	-		
V _{CEsat}	collector-emitter saturation voltage	I _C = 1 A; I _B = 10 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	50	80	mV
		I_C = 1 A; I_B = 50 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	30	50	mV
		$I_C = 2 \text{ A}; I_B = 40 \text{ mA}; \text{ pulsed}; t_p \le 300 \text{ μs}; \delta \le 0.02; T_{amb} = 25 \text{ °C}$	-	60	145	mV
		I _C = 4 A; I _B = 40 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	150	320	mV
		I _C = 4 A; I _B = 200 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	80	150	mV
		I _C = 6 A; I _B = 300 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	120	210	mV
R _{CEsat}	collector-emitter saturation resistance	I _C = 4 A; I _B = 400 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	18	35	mΩ
V _{BEsat}	base-emitter saturation voltage	I _C = 1 A; I _B = 100 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	0.83	0.9	V
		I _C = 4 A; I _B = 400 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	1	1.05	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = 2 V; I _C = 2 A; pulsed; t _p ≤ 300 µs; $\delta \le 0.02$; T _{amb} = 25 °C	-	0.77	0.85	V

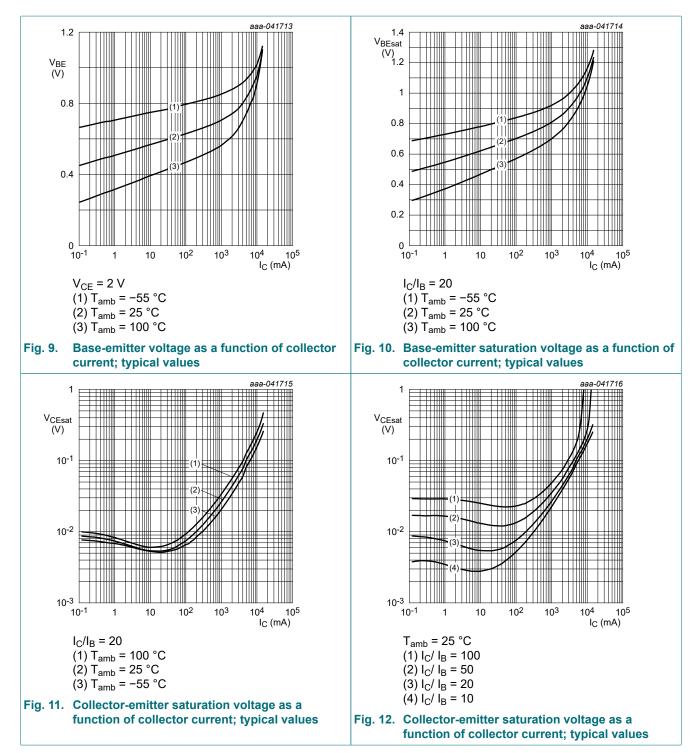
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
t _d	delay time	V _{CC} = 12.5 V; I _C = 1 A; I _{Bon} = 50 mA;	-	35	-	ns
t _r	rise time	I _{Boff} = -50 mA; T _{amb} = 25 °C	-	50	-	ns
t _{on}	turn-on time		-	85	-	ns
t _s	storage time		-	700	-	ns
t _f	fall time		-	120	-	ns
t _{off}	turn-off time		-	820	-	ns
f _T	transition frequency	V_{CE} = 10 V; I _C = 100 mA; f = 100 MHz; T _{amb} = 25 °C	-	125	-	MHz
C _c	collector capacitance	V_{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	30	-	pF

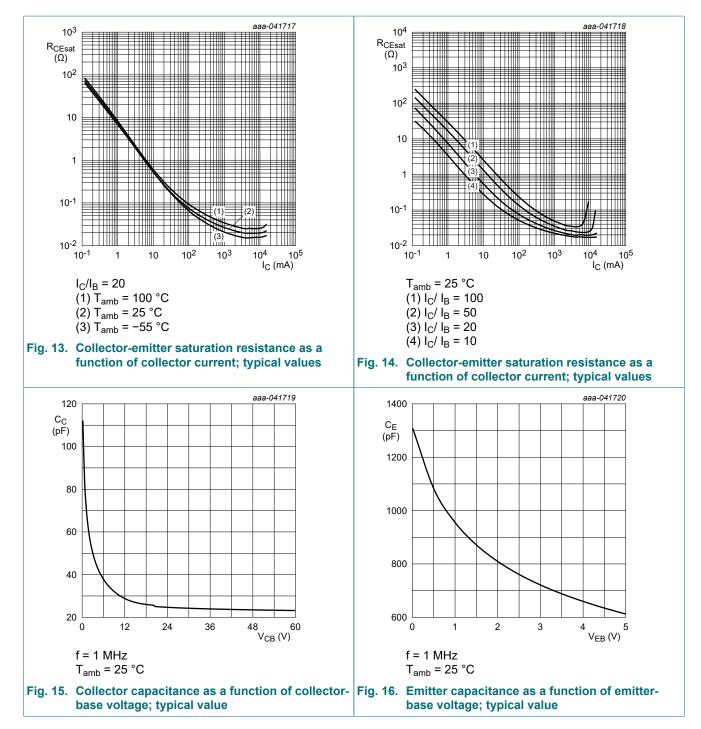


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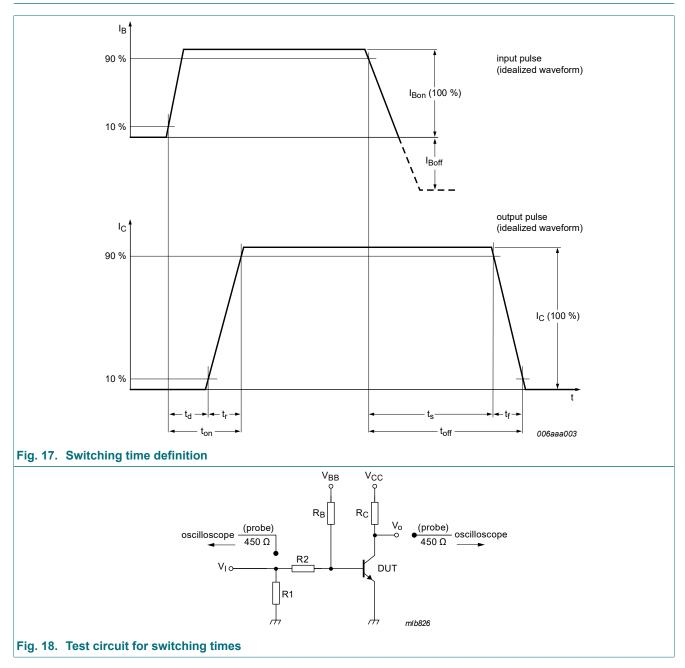


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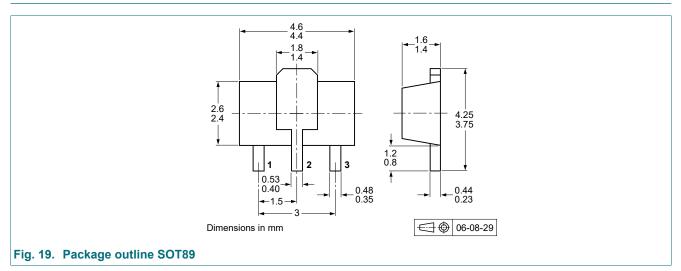
11. Test information



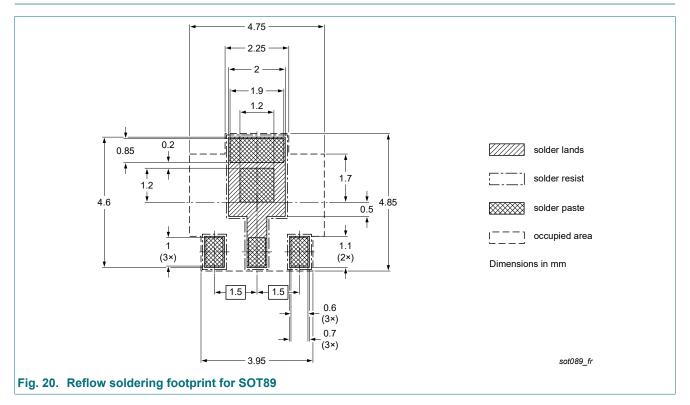
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

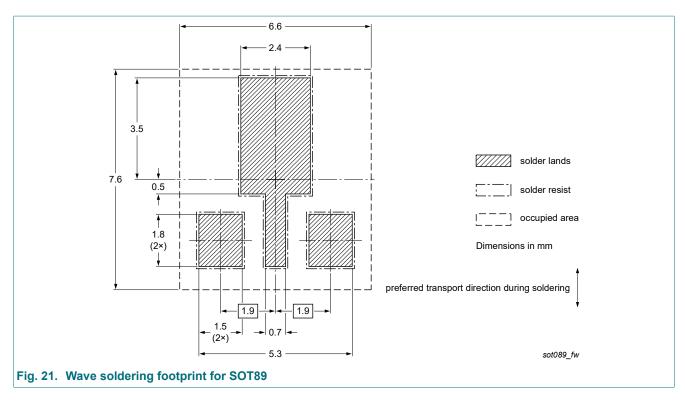
12. Package outline



13. Soldering



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14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBSS4041NX v.4	20250116	Product data sheet	-	PBSS4041NX v.3			
Modifications:		Editorial updateNew graphics and values are added.					
PBSS4041NX v.3	20121211	Product data sheet	-	PBSS4041NX v.2			
PBSS4041NX v.2	20121010	Product data sheet	-	PBSS4041NX v.1			
PBSS4041NX v.1	20100401	Product data sheet	-	-			

PBSS4041NX

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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